# FAIRCHILD

SEMICONDUCTOR®

# FDB8441\_F085

# N-Channel PowerTrench<sup>®</sup> MOSFET 40V, 80A, 2.5m $\Omega$

#### Features

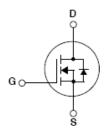
- Typ  $r_{DS(on)}$  = 1.9m $\Omega$  at  $V_{GS}$  = 10V,  $I_D$  = 80A
- Typ Q<sub>g(10)</sub> = 215nC at V<sub>GS</sub> = 10V
- Low Miller Charge
- Low Q<sub>rr</sub> Body Diode
- UIS Capability (Single Pulse and Repetitive Pulse)
- Qualified to AEC Q101
- RoHS Compliant

# AND FREE INNIS MENTA

# Applications

- Automotive Engine Control
- Powertrain Management
- Solenoid and Motor Drivers
- Electronic Steering
- Integrated Starter / Alternator
- Distributed Power Architectures and VRMs
- Primary Switch for 12V Systems





May 2010

Symbol	Parameter		Ratings	Units
V <sub>DS</sub>	Drain to Source Voltage		40	V
V <sub>GS</sub>	Gate to Source Voltage		±20	V
	Drain Current Continuous (T <sub>C</sub> < 160°C, V <sub>GS</sub> = 10V)		80	
I <sub>D</sub>	Continuous ( $T_{amb}$ = 25°C, $V_{GS}$ = 10V, with $R_{\theta JA}$ = 43°C/W)		28	Α
	Pulsed		See Figure 4	
E <sub>AS</sub>	Single Pulse Avalanche Energy (1	Note 1)	947	mJ
П	Power dissipation		300	W
P <sub>D</sub>	Derate above 25°C		2	W/ºC
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature		-55 to 175	°C

### **Thermal Characteristics**

$R_{ ext{ heta}JC}$	Thermal Resistance Junction to Case	0.5	°C/W
$R_{\theta JA}$	Thermal Resistance Junction to Ambient (Note 2	.) 62	°C/W
$R_{\thetaJA}$	Thermal Resistance Junction to Ambient, 1in <sup>2</sup> copper pad area	43	°C/W

# Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDB8441	FDB8441_F085	TO-263AB	330mm	24mm	800 units

# **Electrical Characteristics** $T_J = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
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#### **Off Characteristics**

B <sub>VDSS</sub>	Drain to Source Breakdown Voltage	$I_{D} = 250 \mu A, V_{C}$	as = 0V	40	-	-	V
1	Zero Gate Voltage Drain Current	$V_{DS} = 32V$		-	-	1	μA
DSS	Zero Gale Vollage Drain Current	$V_{GS} = 0V$	$T_J = 150^{\circ}C$	-	-	250	μΑ
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA

#### **On Characteristics**

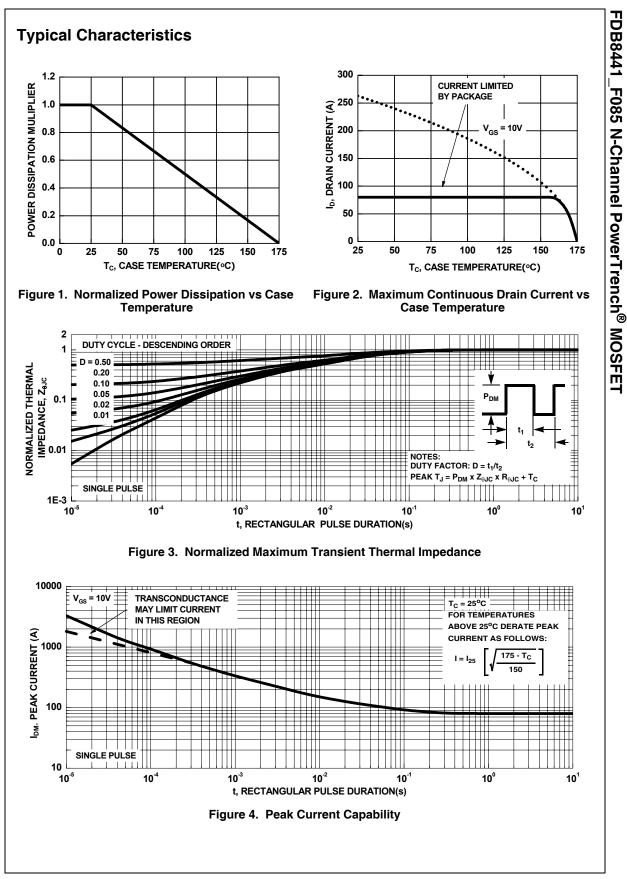
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	2	2.8	4	V
		I <sub>D</sub> = 80A, V <sub>GS</sub> = 10V	-	1.9	2.5	
r <sub>DS(on)</sub>	Drain to Source On Resistance	I <sub>D</sub> = 80A, V <sub>GS</sub> = 10V, T <sub>J</sub> = 175°C	-	3.3	4.3	mΩ

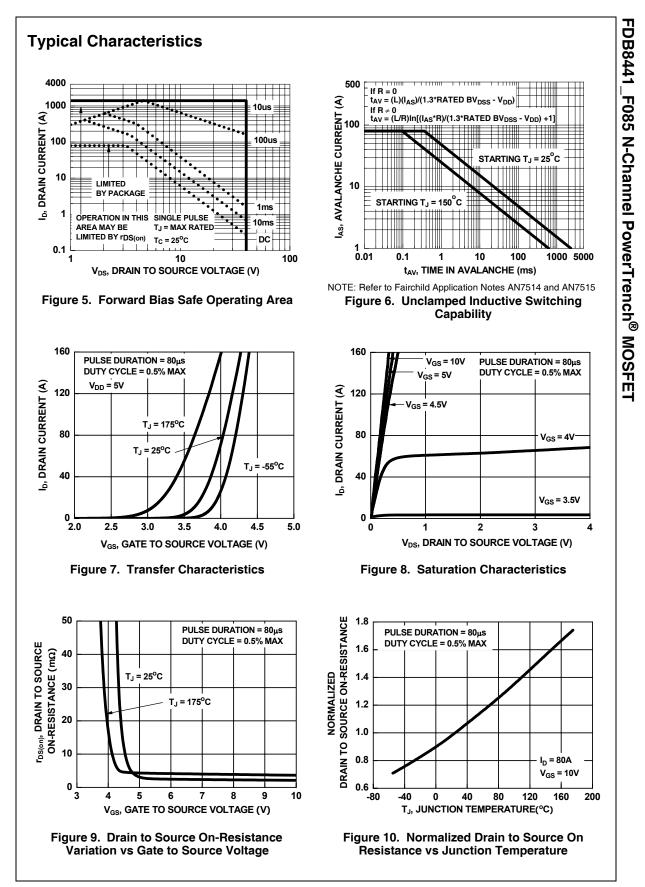
#### **Dynamic Characteristics**

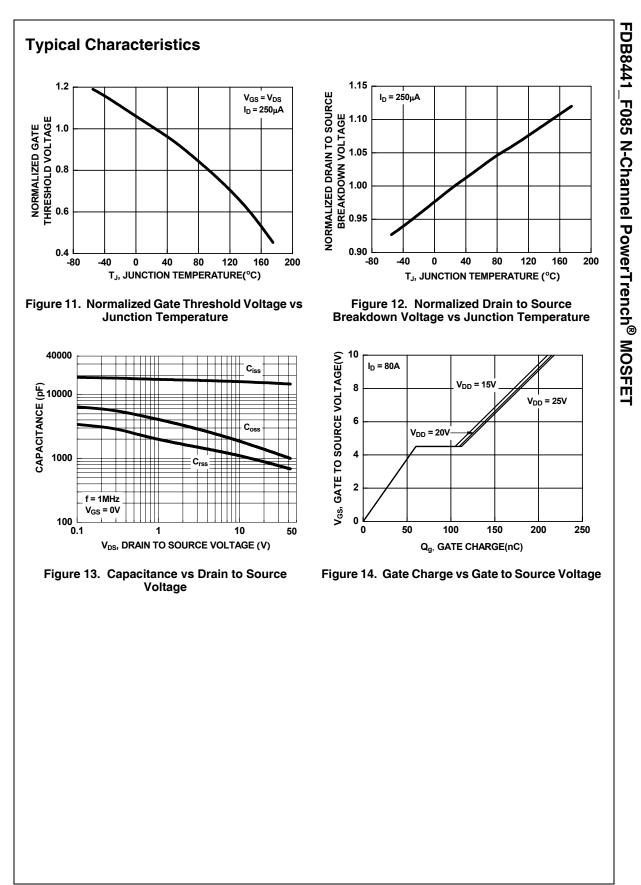
C <sub>iss</sub>	Input Capacitance		0)/	-	15000	-	pF
C <sub>oss</sub>	Output Capacitance	$V_{DS} = 25V, V_{GS} = 0V,$ f = 1MHz		-	1250	-	pF
C <sub>rss</sub>	Reverse Transfer Capacitance			-	685	-	pF
R <sub>G</sub>	Gate Resistance	V <sub>GS</sub> = 0.5V, f = 1	MHz	-	1.1	-	Ω
Q <sub>g(TOT)</sub>	Total Gate Charge at 10V	V <sub>GS</sub> = 0 to 10V		-	215	280	nC
Q <sub>g(TH)</sub>	Threshold Gate Charge	$V_{GS} = 0$ to 2V	$V_{DD} = 20V$	-	29	38	nC
Q <sub>gs</sub>	Gate to Source Gate Charge		I <sub>D</sub> = 35A	-	60	-	nC
Q <sub>gs2</sub>	Gate Charge Threshold to Plateau		l <sub>g</sub> = 1mA	-	32	-	nC
Q <sub>gd</sub>	Gate to Drain "Miller" Charge			-	49	-	nC

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
witching	g Characteristics					
on)	Turn-On Time		-	-	77	ns
d(on)	Turn-On Delay Time	$V_{DD}$ = 20V, I <sub>D</sub> = 35A V <sub>GS</sub> = 10V, R <sub>GS</sub> = 1.5Ω	-	23	-	ns
	Turn-On Rise Time		-	24	-	ns
d(off)	Turn-Off Delay Time		-	75	-	ns
	Turn-Off Fall Time		-	17.9	-	ns
ff	Turn-Off Time		-	17.9 -	- 147	ns ns
n Drain-Sou	Turn-Off Time urce Diode Characteristics	I <sub>SD</sub> = 35A		- 0.8	147 1.25	ns V
<sup>f</sup> ⊅ff <b>)rain-Sou</b> ∕ <sub>SD</sub>	Turn-Off Time	I <sub>SD</sub> = 35A I <sub>SD</sub> = 15A	-	-	147	ns
n Drain-Sou	Turn-Off Time urce Diode Characteristics		-	- 0.8	147 1.25	ns V

V	Source to Drain Diode Voltage	I <sub>SD</sub> = 35A	-	0.8	1.25	V
V <sub>SD</sub>	Source to Drain Diode Voltage	I <sub>SD</sub> = 15A	-	0.8	1.0	V
t <sub>rr</sub>	Reverse Recovery Time	$I_F = 35A$ , di/dt = 100A/µs	-	52	68	ns
Q <sub>rr</sub>	Reverse Recovery Charge	I <sub>F</sub> = 35A, di/dt = 100A/μs	-	76	99	nC







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